

# $\mu$ A7900 SERIES NEGATIVE-VOLTAGE REGULATORS

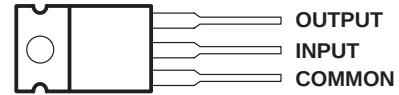
SLVS058A – JUNE 1976 – REVISED OCTOBER 1996

- 3-Terminal Regulators
- Output Current Up to 1.5 A
- No External Components
- Internal Thermal Overload Protection
- High-Power Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Essentially Equivalent to National LM320 Series

## description

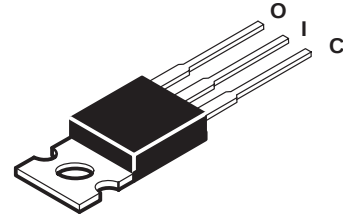
This series of fixed-negative-voltage monolithic integrated-circuit voltage regulators is designed to complement Series  $\mu$ A7800 in a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 1.5 A of output current. The internal current limiting and thermal shutdown features of these regulators make them essentially immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power pass element in precision regulators.

KC PACKAGE  
(TOP VIEW)

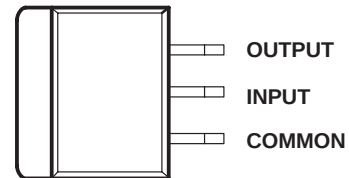


The input terminal is in electrical contact with the mounting base

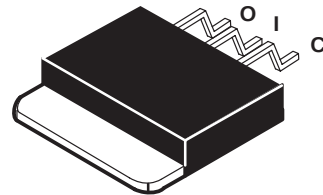
TO-220AB



KTE PACKAGE  
(TOP VIEW)



The input terminal is in electrical contact with the mounting base.



AVAILABLE OPTIONS

| T <sub>A</sub> | V <sub>O(nom)</sub><br>(V) | PACKAGED DEVICES          |                             | CHIP<br>FORM<br>(Y) |
|----------------|----------------------------|---------------------------|-----------------------------|---------------------|
|                |                            | HEAT-SINK MOUNTED<br>(KC) | HEAT-SINK MOUNTED†<br>(KTE) |                     |
| 0°C to 125°C   | –5                         | $\mu$ A7905CKC            | $\mu$ A7905CKTE             | $\mu$ A7905Y        |
|                | –5.2                       | $\mu$ A7952CKC            | $\mu$ A7952CKTE             | $\mu$ A7952Y        |
|                | –6                         | $\mu$ A7906CKC            | $\mu$ A7906CKTE             | $\mu$ A7906Y        |
|                | –8                         | $\mu$ A7908CKC            | $\mu$ A7908CKTE             | $\mu$ A7908Y        |
|                | –12                        | $\mu$ A7912CKC            | $\mu$ A7912CKTE             | $\mu$ A7912Y        |
|                | –15                        | $\mu$ A7915CKC            | $\mu$ A7915CKTE             | $\mu$ A7915Y        |
|                | –18                        | $\mu$ A7918CKC            | $\mu$ A7918CKTE             | $\mu$ A7918Y        |
|                | –24                        | $\mu$ A7924CKC            | $\mu$ A7924CKTE             | $\mu$ A7924Y        |

† The KTE package is also available taped and reeled.



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**TEXAS  
INSTRUMENTS**

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## SLVS058A – JUNE 1976 – REVISED OCTOBER 1996

The diagram illustrates a 4-bit digital-to-analog converter (DAC) circuit. It consists of a 4-bit digital input, a ladder network of resistors and transistors, and a current mirror output stage.

**Input Stage:** The 4-bit digital input is connected to the bases of four transistors. The input voltage range is specified as 5 V to 8 V. The input signal is also connected to the bases of four transistors in the ladder network.

**Ladder Network:** The ladder network is composed of resistors and transistors. The input voltage range is specified as 12 V to 18 V. The ladder network is connected to the output of the current mirror.

**Output Stage:** The output stage is a current mirror circuit. It consists of a reference current source (a resistor connected to a 5 kΩ resistor) and a load resistor (a resistor connected to a 0.2 kΩ resistor). The output voltage is specified as 6.2 V. The output signal is also connected to the bases of four transistors in the ladder network.

**Common:** The common connection is shown at the bottom of the diagram.

All component values are nominal.

|                                                                                                |                               |
|------------------------------------------------------------------------------------------------|-------------------------------|
| Input voltage, $V_I$ : $\mu$ A7924C .....                                                      | -40 V                         |
| All others .....                                                                               | -35 V                         |
| Continuous total power dissipation at (or below): $T_A = 25^\circ\text{C}$ (see Note 1) ...    | See Dissipation Rating Tables |
| $T_C = 90^\circ\text{C}$ (see Note 1) ...                                                      | See Dissipation Rating Tables |
| Operating free-air, $T_A$ , case, $T_C$ , or virtual junction, $T_J$ , temperature range ..... | 0 to $150^\circ\text{C}$      |
| Storage temperature range, $T_{\text{stg}}$ .....                                              | -65 to $150^\circ\text{C}$    |
| Lead temperature 3.2 mm (1/8 inch) from case for 10 seconds .....                              | $260^\circ\text{C}$           |

NOTE 1: For operation above 25°C free-air or 90°C case temperature, refer to Figures 1 and 2. To avoid exceeding the design maximum virtual junction temperature, these ratings should not be exceeded. Due to variations in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

### DISSIPATION RATING TABLE — FREE-AIR TEMPERATURE

| PACKAGE | T <sub>A</sub> ≤ 25°C<br>POWER RATING | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 105°C<br>POWER RATING | T <sub>A</sub> = 125°C<br>POWER RATING |
|---------|---------------------------------------|------------------------------------------------|---------------------------------------|----------------------------------------|----------------------------------------|
| KC      | 2000 mW                               | 16.0 mW/°C                                     | 1280 mW                               | 720 mW                                 | 400 mW                                 |
| KTE     | 1900 mW                               | 15.2 mW/°C                                     | 1216 mW                               | 684 mW                                 | 380 mW                                 |

### DISSIPATION RATING TABLE — CASE TEMPERATURE

| PACKAGE | T <sub>C</sub> ≤ 90°C<br>POWER RATING | DERATING FACTOR<br>ABOVE T <sub>C</sub> = 90°C | T <sub>A</sub> = 125°C<br>POWER RATING |
|---------|---------------------------------------|------------------------------------------------|----------------------------------------|
| KC      | 15000 mW                              | 250.0 mW/°C                                    | 6250 mW                                |
| KTE     | 14300 mW                              | 238.0 mW/°C                                    | 5970 mW                                |

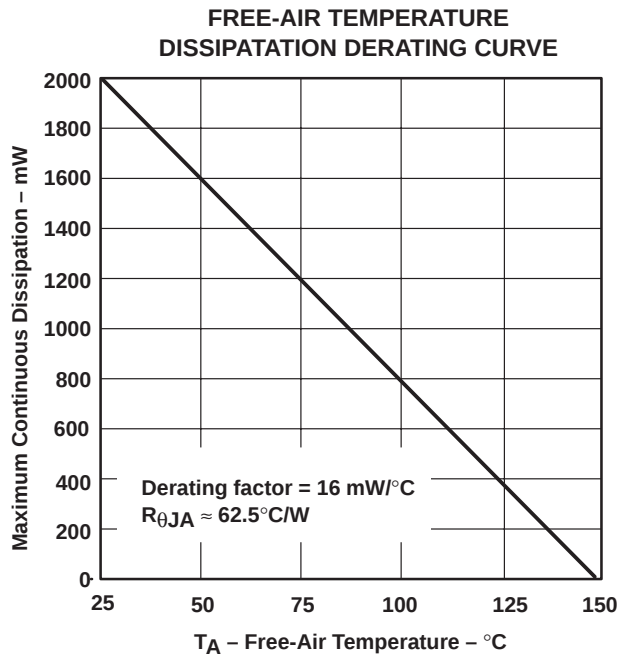


Figure 1

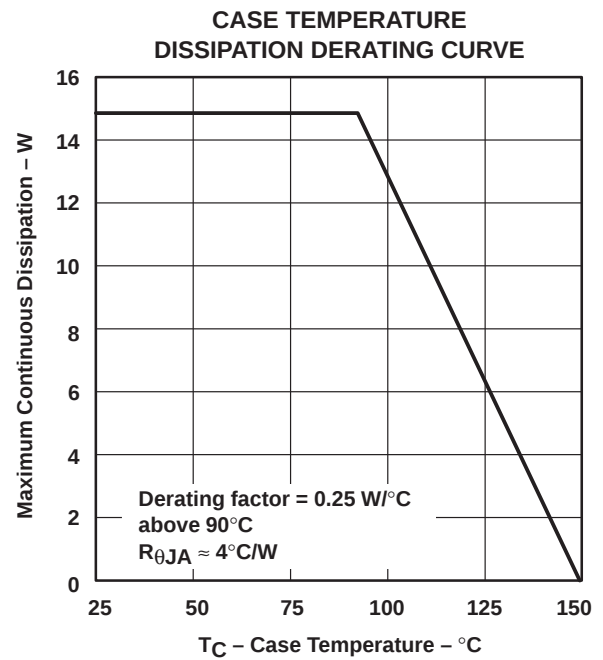


Figure 2

### recommended operating conditions

|                                               |         | MIN   | MAX | UNIT |
|-----------------------------------------------|---------|-------|-----|------|
| Input voltage, $V_I$                          | μA7905C | -7    | -25 | V    |
|                                               | μA7952C | -7.2  | -25 |      |
|                                               | μA7906C | -8    | -25 |      |
|                                               | μA7908C | -10.5 | -25 |      |
|                                               | μA7912C | -14.5 | -30 |      |
|                                               | μA7915C | -17.5 | -30 |      |
|                                               | μA7918C | -21   | -33 |      |
|                                               | μA7924C | -27   | -28 |      |
| Output current, $I_O$                         |         |       | 1.5 | A    |
| Operating virtual junction temperature, $T_J$ |         | 0     | 125 | °C   |

# **μA7900 SERIES** **NEGATIVE-VOLTAGE REGULATORS**

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**electrical characteristics at specified virtual junction temperature,  $V_I = -10$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                              | $T_J^\dagger$ | μA7905C |      |       | UNITS |
|-------------------------------------------|--------------------------------------------------------------|---------------|---------|------|-------|-------|
|                                           |                                                              |               | MIN     | TYP  | MAX   |       |
| Output voltage <sup>‡</sup>               |                                                              | 25°C          | -4.8    | -5   | -5.2  | V     |
|                                           | $I_O = 5$ mA to 1 A,<br>$P \leq 15$ W $V_I = -7$ V to -20 V, | 0°C to 125°C  | -4.75   |      | -5.25 |       |
| Input regulation                          | $V_I = -7$ V to -25 V                                        |               |         | 12.5 | 50    | mV    |
|                                           | $V_I = -8$ V to -12 V                                        |               |         | 4    | 15    |       |
| Ripple rejection                          | $V_I = -8$ V to -18 V, $f = 120$ Hz                          | 0°C to 125°C  | 54      | 60   |       | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                        |               |         | 15   | 100   | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                     |               |         | 5    | 50    |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                                 | 0°C to 125°C  |         | -0.4 |       | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                       | 25°C          |         | 125  |       | μV    |
| Dropout voltage                           | $I_O = 1$ A                                                  | 25°C          |         | 1.1  |       | V     |
| Bias current                              |                                                              | 25°C          |         | 1.5  | 2     | mA    |
| Bias current change                       | $V_I = -7$ V to -25 V                                        |               |         | 0.15 | 0.5   | mA    |
|                                           | $I_O = 5$ mA to 1 A                                          |               |         | 0.08 | 0.5   |       |
| Peak output current                       |                                                              | 25°C          |         | 2.1  |       | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

<sup>‡</sup> This specification applies only for dc power dissipation permitted by absolute maximum ratings.

**electrical characteristics at specified virtual junction temperature,  $V_I = -10$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                                | $T_J^\dagger$ | μA7952C |      |       | UNITS |
|-------------------------------------------|----------------------------------------------------------------|---------------|---------|------|-------|-------|
|                                           |                                                                |               | MIN     | TYP  | MAX   |       |
| Output voltage <sup>‡</sup>               |                                                                | 25°C          | -5      | -5.2 | -5.4  | V     |
|                                           | $I_O = 5$ mA to 1 A,<br>$P \leq 15$ W $V_I = -7.2$ V to -20 V, | 0°C to 125°C  | -4.95   |      | -5.45 |       |
| Input regulation                          | $V_I = -7.2$ V to -25 V                                        |               |         | 12.5 | 100   | mV    |
|                                           | $V_I = -8.2$ V to -12 V                                        |               |         | 4    | 50    |       |
| Ripple rejection                          | $V_I = -8.2$ V to -18 V, $f = 120$ Hz                          | 0°C to 125°C  | 54      | 60   |       | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                          |               |         | 15   | 100   | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                       |               |         | 5    | 50    |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                                   | 0°C to 125°C  |         | -0.4 |       | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                         | 25°C          |         | 125  |       | μV    |
| Dropout voltage                           | $I_O = 1$ A                                                    | 25°C          |         | 1.1  |       | V     |
| Bias current                              |                                                                | 25°C          |         | 1.5  | 2     | mA    |
| Bias current change                       | $V_I = -7.2$ V to -25 V                                        |               |         | 0.15 | 1.3   | mA    |
|                                           | $I_O = 5$ mA to 1 A                                            |               |         | 0.08 | 0.5   |       |
| Peak output current                       |                                                                | 25°C          |         | 2.1  |       | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

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# μA7900 SERIES NEGATIVE-VOLTAGE REGULATORS

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**electrical characteristics at specified virtual junction temperature,  $V_I = -11$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                           | $T_J^\dagger$ | μA7906C |      |       | UNITS |
|-------------------------------------------|-----------------------------------------------------------|---------------|---------|------|-------|-------|
|                                           |                                                           |               | MIN     | TYP  | MAX   |       |
| Output voltage <sup>‡</sup>               |                                                           | 25°C          | -5.75   | -6   | -6.25 | V     |
|                                           | $I_O = 5$ mA to 1 A, $V_I = -8$ V to -21 V, $P \leq 15$ W | 0°C to 125°C  | -5.7    |      | -6.3  |       |
| Input regulation                          | $V_I = -8$ V to -25 V                                     |               |         | 12.5 | 120   | mV    |
|                                           | $V_I = -9$ V to -13 V                                     |               |         | 4    | 60    |       |
| Ripple rejection                          | $V_I = -9$ V to -19 V, $f = 120$ Hz                       | 0°C to 125°C  | 54      | 60   |       | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                     |               |         | 15   | 120   | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                  |               |         | 5    | 60    |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                              | 0°C to 125°C  |         | -0.4 |       | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                    | 25°C          |         | 150  |       | μV    |
| Dropout voltage                           | $I_O = 1$ A                                               | 25°C          |         | 1.1  |       | V     |
| Bias current                              |                                                           | 25°C          |         | 1.5  | 2     | mA    |
| Bias current change                       | $V_I = -8$ V to -25 V                                     |               |         | 0.15 | 1.3   | mA    |
|                                           | $I_O = 5$ mA to 1 A                                       |               |         | 0.08 | 0.5   |       |
| Peak output current                       |                                                           | 25°C          |         | 2.1  |       | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

<sup>‡</sup> This specification applies only for dc power dissipation permitted by absolute maximum ratings.

**electrical characteristics at specified virtual junction temperature,  $V_I = -14$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                              | $T_J^\dagger$ | μA7908C |      |      | UNITS |
|-------------------------------------------|--------------------------------------------------------------|---------------|---------|------|------|-------|
|                                           |                                                              |               | MIN     | TYP  | MAX  |       |
| Output voltage <sup>‡</sup>               |                                                              | 25°C          | -7.7    | -8   | -8.3 | V     |
|                                           | $I_O = 5$ mA to 1 A, $V_I = -10.5$ V to -23 V, $P \leq 15$ W | 0°C to 125°C  | -7.6    |      | -8.4 |       |
| Input regulation                          | $V_I = -10.5$ V to -25 V                                     |               |         | 12.5 | 160  | mV    |
|                                           | $V_I = -11$ V to -17 V                                       |               |         | 4    | 80   |       |
| Ripple rejection                          | $V_I = -11.5$ V to -21.5 V, $f = 120$ Hz                     | 0°C to 125°C  | 54      | 60   |      | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                        |               |         | 15   | 160  | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                     |               |         | 5    | 80   |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                                 | 0°C to 125°C  |         | -0.6 |      | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                       | 25°C          |         | 200  |      | μV    |
| Dropout voltage                           | $I_O = 1$ A                                                  | 25°C          |         | 1.1  |      | V     |
| Bias current                              |                                                              | 25°C          |         | 1.5  | 2    | mA    |
| Bias current change                       | $V_I = -10.5$ V to -25 V                                     |               |         | 0.15 | 1    | mA    |
|                                           | $I_O = 5$ mA to 1 A                                          |               |         | 0.08 | 0.5  |       |
| Peak output current                       |                                                              | 25°C          |         | 2.1  |      | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

<sup>‡</sup> This specification applies only for dc power dissipation permitted by absolute maximum ratings.



# **μA7900 SERIES** **NEGATIVE-VOLTAGE REGULATORS**

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**electrical characteristics at specified virtual junction temperature,  $V_I = -19$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                              | $T_J^\dagger$ | μA7912C |      |       | UNITS |
|-------------------------------------------|--------------------------------------------------------------|---------------|---------|------|-------|-------|
|                                           |                                                              |               | MIN     | TYP  | MAX   |       |
| Output voltage <sup>‡</sup>               |                                                              | 25°C          | -11.5   | -12  | -12.5 | V     |
|                                           | $I_O = 5$ mA to 1 A, $V_I = -14.5$ V to -27 V, $P \leq 15$ W | 0°C to 125°C  | -11.4   |      | -12.6 |       |
| Input regulation                          | $V_I = -14.5$ V to -30 V                                     |               |         | 5    | 80    | mV    |
|                                           | $V_I = -16$ V to -22 V                                       |               |         | 3    | 30    |       |
| Ripple rejection                          | $V_I = -15$ V to -25 V, $f = 120$ Hz                         | 0°C to 125°C  | 54      | 60   |       | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                        |               |         | 15   | 200   | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                     |               |         | 5    | 75    |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                                 | 0°C to 125°C  |         | -0.8 |       | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                       | 25°C          |         | 300  |       | μV    |
| Dropout voltage                           | $I_O = 1$ A                                                  | 25°C          |         | 1.1  |       | V     |
| Bias current                              |                                                              | 25°C          |         | 2    | 3     | mA    |
| Bias current change                       | $V_I = -14.5$ V to -30 V                                     |               |         | 0.04 | 0.5   | mA    |
|                                           | $I_O = 5$ mA to 1 A                                          |               |         | 0.06 | 0.5   |       |
| Peak output current                       |                                                              | 25°C          |         | 2.1  |       | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

<sup>‡</sup> This specification applies only for dc power dissipation permitted by absolute maximum ratings.

**electrical characteristics at specified virtual junction temperature,  $V_I = -23$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                              | $T_J^\dagger$ | μA7915C |      |        | UNITS |
|-------------------------------------------|--------------------------------------------------------------|---------------|---------|------|--------|-------|
|                                           |                                                              |               | MIN     | TYP  | MAX    |       |
| Output voltage <sup>‡</sup>               |                                                              | 25°C          | -14.4   | -15  | -15.6  | V     |
|                                           | $I_O = 5$ mA to 1 A, $V_I = -17.5$ V to -30 V, $P \leq 15$ W | 0°C to 125°C  | -14.25  |      | -15.75 |       |
| Input regulation                          | $V_I = -17.5$ V to -30 V                                     |               |         | 5    | 100    | mV    |
|                                           | $V_I = -20$ V to -26 V                                       |               |         | 3    | 50     |       |
| Ripple rejection                          | $V_I = -18.5$ V to -28.5 V, $f = 120$ Hz                     | 0°C to 125°C  | 54      | 60   |        | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                        |               |         | 20   | 300    | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                     |               |         | 8    | 150    |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                                 | 0°C to 125°C  |         | -1   |        | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                       | 25°C          |         | 375  |        | μV    |
| Dropout voltage                           | $I_O = 1$ A                                                  | 25°C          |         | 1.1  |        | V     |
| Bias current                              |                                                              | 25°C          |         | 2    | 3      | mA    |
| Bias current change                       | $V_I = -17.5$ V to -30 V                                     |               |         | 0.04 | 0.5    | mA    |
|                                           | $I_O = 5$ mA to 1 A                                          |               |         | 0.06 | 0.5    |       |
| Peak output current                       |                                                              | 25°C          |         | 2.1  |        | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

<sup>‡</sup> This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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# μA7900 SERIES NEGATIVE-VOLTAGE REGULATORS

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**electrical characteristics at specified virtual junction temperature,  $V_I = -27$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                            | $T_J^\dagger$ | μA7918C |      |       | UNITS |
|-------------------------------------------|------------------------------------------------------------|---------------|---------|------|-------|-------|
|                                           |                                                            |               | MIN     | TYP  | MAX   |       |
| Output voltage <sup>‡</sup>               |                                                            | 25°C          | -17.3   | -18  | -18.7 | V     |
|                                           | $I_O = 5$ mA to 1 A, $V_I = -21$ V to -33 V, $P \leq 15$ W | 0°C to 125°C  | -17.1   |      | -18.9 |       |
| Input regulation                          | $V_I = -21$ V to -33 V                                     |               |         | 5    | 360   | mV    |
|                                           | $V_I = -24$ V to -30 V                                     |               |         | 3    | 180   |       |
| Ripple rejection                          | $V_I = -22$ V to -32 V, $f = 120$ Hz                       | 0°C to 125°C  | 54      | 60   |       | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                      |               |         | 30   | 360   | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                   |               |         | 10   | 180   |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                               | 0°C to 125°C  |         | -1   |       | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                     | 25°C          |         | 450  |       | μV    |
| Dropout voltage                           | $I_O = 1$ A                                                | 25°C          |         | 1.1  |       | V     |
| Bias current                              |                                                            | 25°C          |         | 2    | 3     | mA    |
| Bias current change                       | $V_I = -21$ V to -33 V                                     |               |         | 0.04 | 1     | mA    |
|                                           | $I_O = 5$ mA to 1 A                                        |               |         | 0.06 | 0.5   |       |
| Peak output current                       |                                                            | 25°C          |         | 2.1  |       | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

<sup>‡</sup> This specification applies only for dc power dissipation permitted by absolute maximum ratings.

**electrical characteristics at specified virtual junction temperature,  $V_I = -33$  V,  $I_O = 500$  mA (unless otherwise noted)**

| PARAMETER                                 | TEST CONDITIONS                                            | $T_J^\dagger$ | μA7924C |      |       | UNITS |
|-------------------------------------------|------------------------------------------------------------|---------------|---------|------|-------|-------|
|                                           |                                                            |               | MIN     | TYP  | MAX   |       |
| Output voltage <sup>‡</sup>               |                                                            | 25°C          | -23     | -24  | -25   | V     |
|                                           | $I_O = 5$ mA to 1 A, $V_I = -27$ V to -38 V, $P \leq 15$ W | 0°C to 125°C  | -22.8   |      | -25.2 |       |
| Input regulation                          | $V_I = -27$ V to -38 V                                     |               |         | 5    | 480   | mV    |
|                                           | $V_I = -30$ V to -36 V                                     |               |         | 3    | 240   |       |
| Ripple rejection                          | $V_I = -28$ V to -38 V, $f = 120$ Hz                       | 0°C to 125°C  | 54      | 60   |       | dB    |
| Output regulation                         | $I_O = 5$ mA to 1.5 A                                      |               |         | 85   | 480   | mV    |
|                                           | $I_O = 250$ mA to 750 mA                                   |               |         | 25   | 240   |       |
| Temperature coefficient of output voltage | $I_O = 5$ mA                                               | 0°C to 125°C  |         | -1   |       | mV/°C |
| Output noise voltage                      | $f = 10$ Hz to 100 kHz                                     | 25°C          |         | 600  |       | μV    |
| Dropout voltage                           | $I_O = 1$ A                                                | 25°C          |         | 1.1  |       | V     |
| Bias current                              |                                                            | 25°C          |         | 2    | 3     | mA    |
| Bias current change                       | $V_I = -27$ V to -38 V                                     |               |         | 0.04 | 1     | mA    |
|                                           | $I_O = 5$ mA to 1 A                                        |               |         | 0.06 | 0.5   |       |
| Peak output current                       |                                                            | 25°C          |         | 2.1  |       | A     |

<sup>†</sup> Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output.

<sup>‡</sup> This specification applies only for dc power dissipation permitted by absolute maximum ratings.



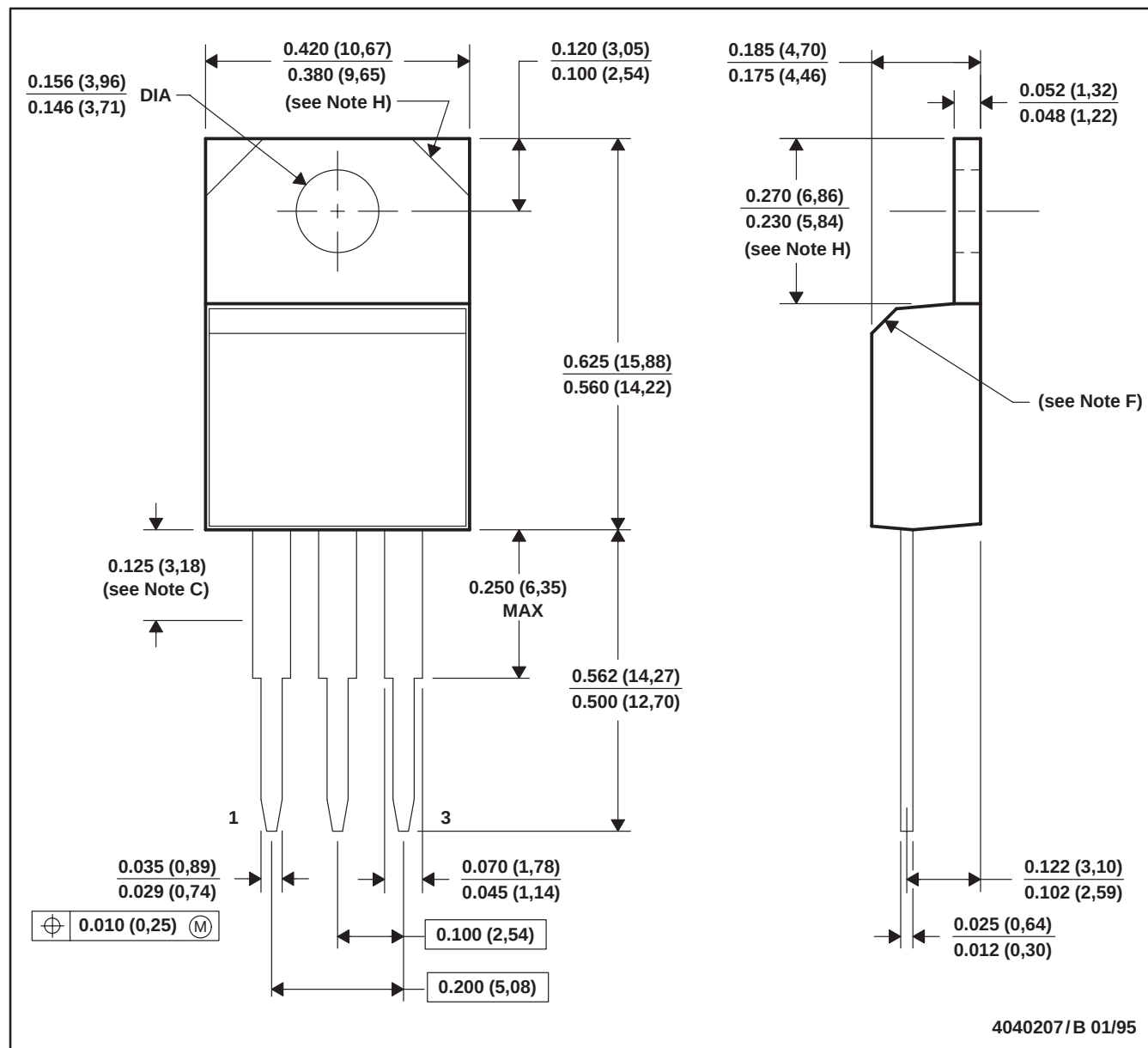
# **μA7900 SERIES** **NEGATIVE-VOLTAGE REGULATORS**

SLVS058A – JUNE 1976 – REVISED OCTOBER 1996

## **MECHANICAL INFORMATION**

**KC (R-PSFM-T3)**

**PLASTIC FLANGE-MOUNT PACKAGE**

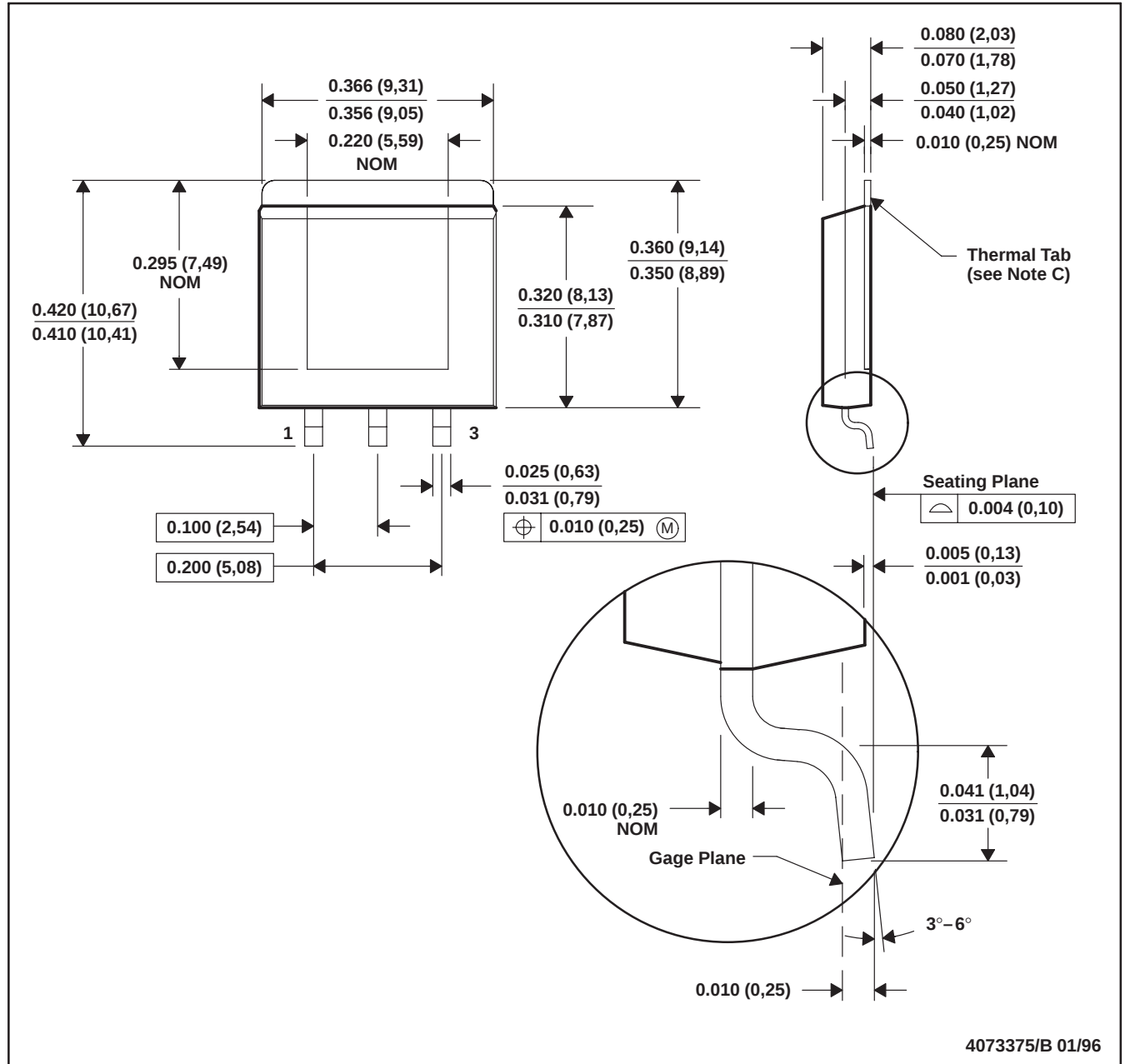


- NOTES: A. All linear dimensions are in inches (millimeters).  
 B. This drawing is subject to change without notice.  
 C. Lead dimensions are not controlled within this area.  
 D. All lead dimensions apply before solder dip.  
 E. The center lead is in electrical contact with the mounting tab.  
 F. The chamfer is optional.  
 G. Falls within JEDEC TO-220AB  
 H. Tab contour optional within these dimensions

**MECHANICAL INFORMATION**

**KTE (R-PSFM-T3)**

**PLASTIC FLANGE-MOUNT PACKAGE**



NOTES: A. All linear dimensions are in inches (millimeters).  
B. This drawing is subject to change without notice.  
C. The center lead is in electrical contact with the thermal tab.

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